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Self-activated ultrahigh chemosensitivity of oxide thin film nanostructures for transparent sensors

SUBJECT AREAS:

ELECTRONIC MATERIALS
AND DEVICES

SENSORS

MATERIALS PHYSICS

APPLIED PHYSICS

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One of the top design priorities for semiconductor chemical sensors is developing simple, low-cost, sensitive and reliable sensors to be built in handheld devices. However, the need to implement heating elements in sensor devices, and the resulting high power consumption, remains a major obstacle for the realization of miniaturized and integrated chemoresistive thin film sensors based on metal oxides. Here we demonstrate structurally simple but extremely efficient all oxide chemoresistive sensors with ~90% transmittance at visible wavelengths. Highly effective self-activation in anisotropically self-assembled nanocolumnar tungsten oxide thin films on glass substrate with indium-tin oxide electrodes enables ultrahigh response to nitrogen dioxide and volatile organic compounds with detection limits down to parts per trillion levels and power consumption less than 0.2 microwatts. Beyond the sensing performance, high transparency at visible wavelengths creates opportunities for their use in transparent electronic circuitry and optoelectronic devices with avenues for further functional convergence.

Smart sensors, offering real-time analysis of gaseous chemical analytes, are essentials for environmental emissions monitoring, fossil fuel combustion control, medical diagnosis, artificial olfaction and homeland security^{1–9}. Simplicity in operation, low cost, flexibility in production and small size constitute the main advantages of chemoresistive-type semiconductor chemical sensors based on metal oxides over electrochemical, optical, acoustic and other types of chemical sensors^{10–15}. To insure rapid and reversible operation of such sensors, which rely on adsorption and desorption of molecules on the surface of semiconducting materials, the operation temperature is typically maintained between 200 and 400°C^{10,11}. This requires the integration of heating elements within sensor devices with power consumption as high as hundreds of mW. Micromachined silicon platforms reduce the power consumption down to tens of mW¹⁶, but this still remains a burden for portable devices operating with batteries. Ultralow power consumption of chemical sensors based on self-heated individual metal oxide nanowires¹⁷ or nanobelts¹⁸ have been reported, but these typically are insufficiently sensitive and/or are difficult to integrate with low-cost and high-yield mass production processes¹⁹. In addition to power consumption, high temperature operation of conventional semiconductor chemical sensors based on thin or thick films composed of metal oxide nanoparticles results in long-term instability, reflected in the drift of both sensor resistance and response⁹. Highly sensitive devices rely on the response of metal oxide nanoparticles within a thin or thick film matrix, which tend to aggregate and coarsen into larger secondary particles in order to lower their surface energies^{20,21}. The aggregation reduces film porosity and hampers the in-diffusion of chemical analytes. The coarsening leads to the decreased carrier modulation efficiency within the particles²². Although pre-aging



thermal treatments at higher temperatures can improve long-term stability, the complete elimination of thermal degradation remains a problem, unless the operation temperature can be reduced below 200°C, where grain growth normally initiates for nanoparticles of a few nm dimension²³. At the same time, lowering the operation temperature below 200°C normally compromises sensitivity and response kinetics, as discussed above. Therefore, obtaining highly sensitive chemical sensors that operate at low temperatures (< 200°C) remains a challenging issue.

The key objective of this study is to achieve highly sensitive and stable chemoresistive metal oxide sensors with low power consumption by the nanostructuring of the sensing films which is designed for efficient self-activation. The response of sensing films to chemical analytes significantly increases as the feature sizes of the nanostructures approach the Debye length^{24–26}. Using self-activation, the volume of the heated portion of the sensor can be minimized, while the heat dissipation to the substrate and ambient is dramatically reduced. Stable and extended operation is exploited by adjusting the working temperature of the sensing film via self-activation. Another key objective is to develop optically transparent high performance sensors with potential for being integrated into transparent electronics, automobile windshields and other transparent devices.

We believe such work would create a new paradigm for chemical sensors with opportunities in a wide range of here-to-fore untapped applications.

Results

The fabrication process of transparent chemical sensors in which commercially available indium-tin oxide (ITO)-coated glass was used as the substrate is shown in Fig. 1a. ITO interdigitated electrodes (IDEs) with interspacing of 5 μm were patterned by dry etching. Porous WO₃ thin films were deposited onto the IDEs by glancing angle deposition (GAD) via RF sputtering. GAD utilizes the self-shadowing effect of initial nuclei to grow inclined nanowires, nanorods or nanocolumns^{27–29}. The nature of the oxide nanostructures grown by GAD depends largely on the material being sputtered²⁷. For example, porous nanostructures were obtained for WO₃ and Nb₂O₅, whereas In₂O₃, TiO₂, SnO₂ and ZnO formed relatively dense films under the same deposition condition (Supplementary Fig. S1). The size and density of the initial nuclei, which depend on the metal element, appear to be key parameters in determining the final nanostructure. Oxides composed of higher melting temperature metal elements result in more highly porous structures. Films with microstructural elements exhibiting high length to diameter aspect ratios

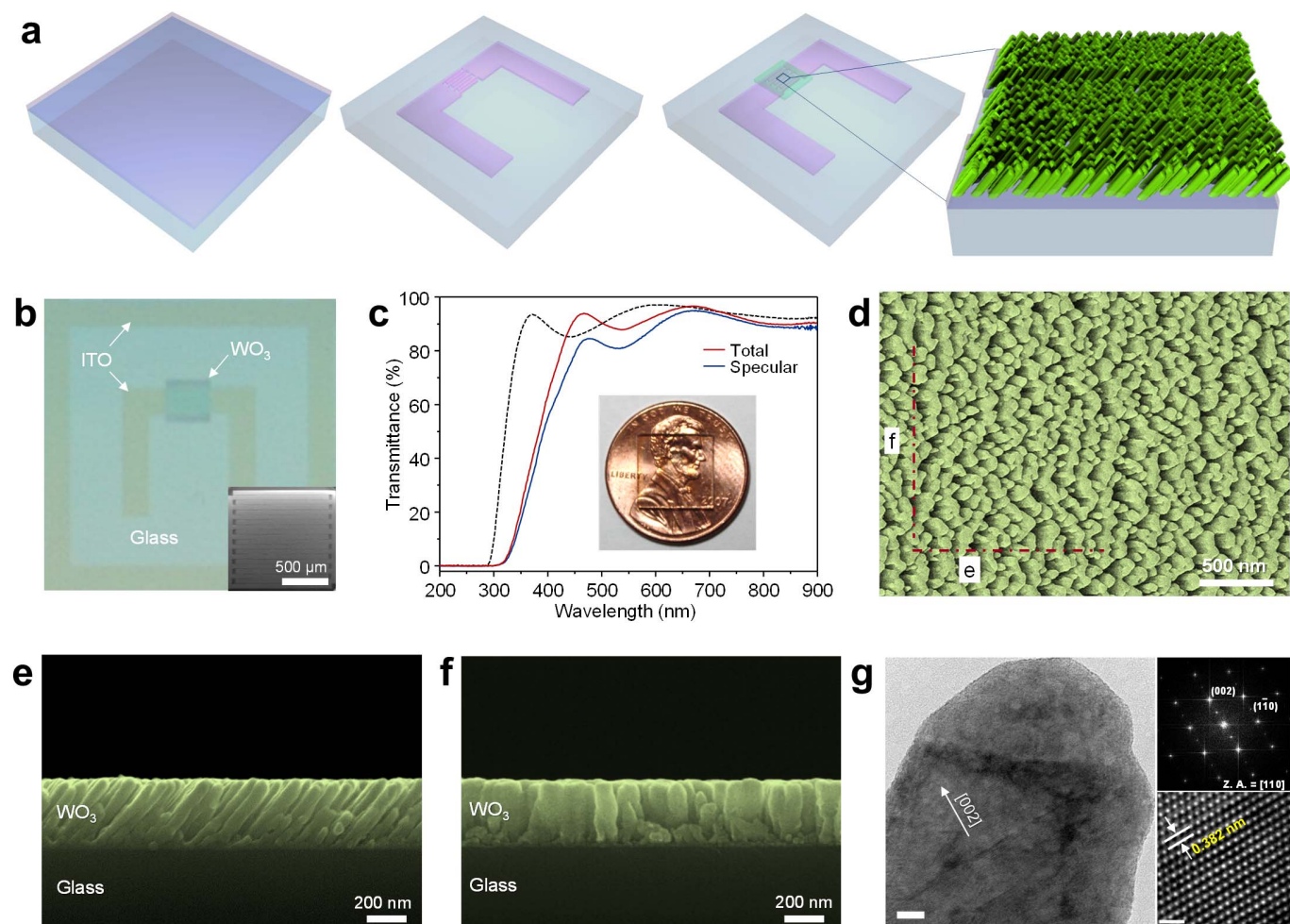


Figure 1 | Transparent sensors based on nanocolumnar WO₃ thin films. (a) Schematic showing the fabrication process of transparent sensors based on nanocolumnar oxide films. (b) Photograph of a fabricated sensor. Inset: SEM image of nanocolumnar WO₃ film on ITO IDEs. (c) Total and specular transmittance spectra of the nanocolumnar WO₃ film/ITO IDEs/glass sensor structure. For reference, the total transmittance spectrum of the ITO/glass substrate is presented (dash line). Inset: photograph of a sensor on a coin (penny). (d) Plain-view SEM image of the nanocolumnar WO₃ film between ITO IDEs. (e), (f) Cross-sectional SEM images of the nanocolumnar WO₃ film cut along (e) and across (f) the ITO IDEs as marked in (d). (g) High-resolution TEM image of a WO₃ nanocolumn. Scale bar, 10 nm. Right: selected area diffraction pattern with zone axis of [110] (top) and lattice image of WO₃ with interplanar spacing of 0.382 nm corresponding to the (002) plane (bottom). Scale bar, 1 nm.



are described as nanocolumnar. An example is the 330-nm-thick porous WO_3 thin film, with column diameters of 30–80 nm and aspect ratios, ranging from 5 to 8.

Figure 1b shows a photograph of a fabricated sensor where the nanocolumnar WO_3 sensing film on ITO IDEs looks smooth macroscopically. The total and specular transmittance spectra of the nanocolumnar WO_3 film/ITO IDEs/glass sensor structure, measured from 200 nm to 900 nm, are shown in Fig. 1c. The longer onset absorption wavelengths of the sensor relative to that of the ITO/glass substrate are due to the smaller optical band gap of WO_3 (3.0 eV) compared to that of ITO (3.9 eV)³⁰. After averaging the oscillations in the spectrum due to optical interference effects, the total transmittance of the sensor over 450–900 nm is determined to be 90.2%, nearly identical to the transmittance of the ITO/glass substrate by itself. Owing to this high transmittance, the fabricated sensors are barely visible, as shown in the inset of Fig. 1c, suggesting that these sensors could be embedded in next-generation smart displays equipped with transparent electronics for automobile, biomedical, military, aerospace, and consumer applications³¹. With a maximum difference of 14% at 440 nm, the 1.5% lower specular transmittance, on average, compared to the total transmittance

means that light scattering likely takes place due to the presence of pores and local variations in the lengths of WO_3 nanocolumns. Upon closer examination, it becomes apparent that the nanocolumnar WO_3 films exhibit structural anisotropy (Fig. 1d). The cross-sectional scanning electron microscopy (SEM) image of the films between the IDEs, cut parallel with the direction of the IDEs, show arrays of canted nanocolumns separated from each other by elongated pores which extend over nearly the full thickness of the film (Fig. 1e). In contrast, the nanocolumns are connected each other and form walls with considerably higher density across the IDEs (Fig. 1f). The pores facilitate access of gaseous molecules to the bottom of the columnar film, while the dense connected nanocolumns across the IDEs provide efficient pathways for electrical current flow. The separation of the individual nanocolumns grown between the IDEs is seen more clearly by the cross-sectional transmission electron microscopy (TEM) images (Supplementary Fig. S2). High-resolution TEM (Fig. 1g) show that each nanocolumn has high crystallinity and (002) preferred orientation, even though the overall WO_3 film with a monoclinic structure is polycrystalline as indicated by X-ray diffraction (Supplementary Fig. S2). By analysing the selected area diffraction patterns from TEM and X-ray

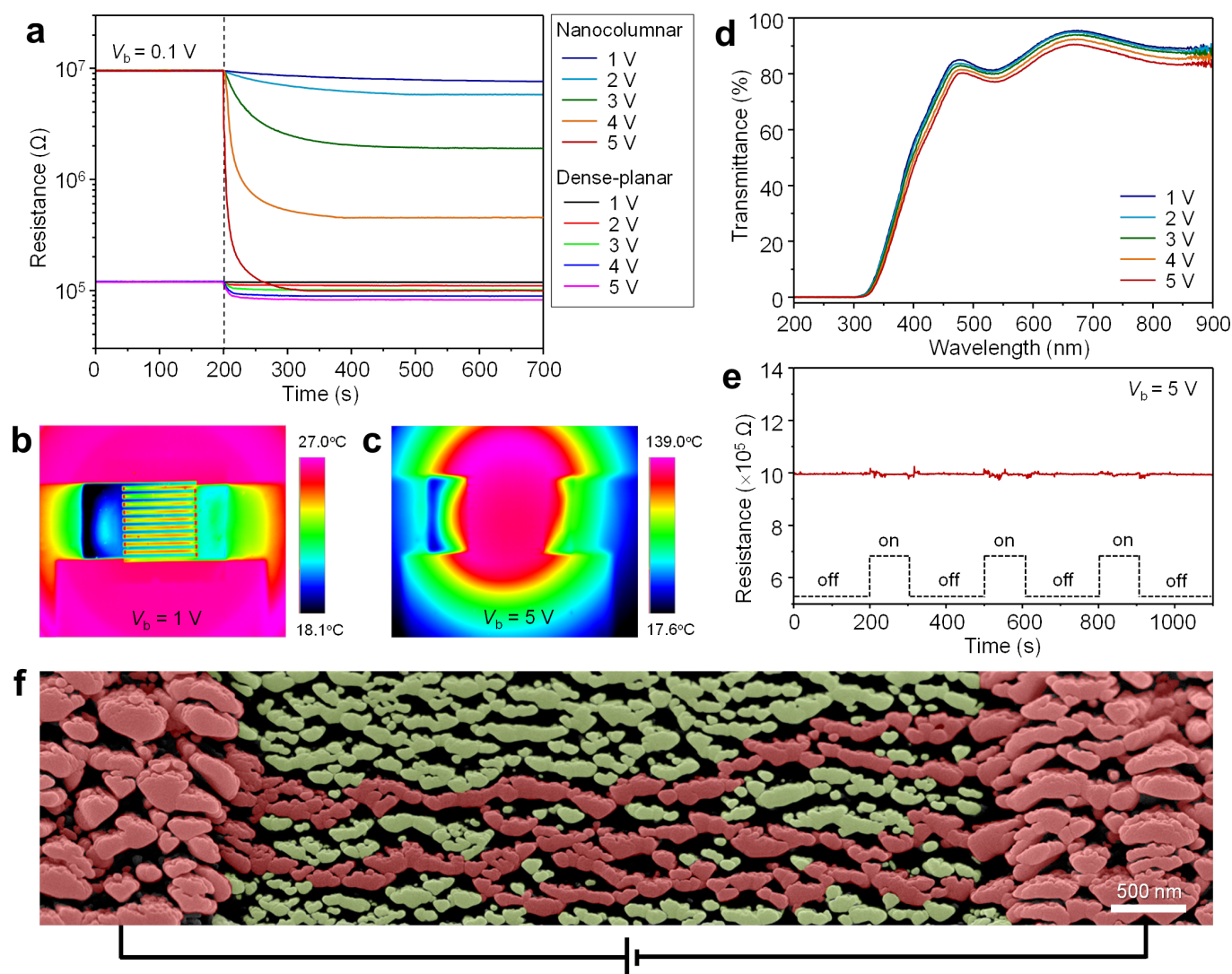


Figure 2 | Self-activation. (a) Resistance-time characteristics with variation of applied bias voltage for dense-planar and nanocolumnar WO_3 thin film sensors. (b), (c) Thermographic images showing temperature variation in the WO_3 thin film sensors with different bias voltages (V_b). (d) Bias-voltage-dependent specular transmittance spectra of the nanocolumnar WO_3 film/ITO IDEs/glass sensor structure. (e) Response of the nanocolumnar WO_3 thin film sensor to office fluorescent light with a luminance of about 400 lx showing no change in device resistance. (f) 40°-tilted SEM image of nanocolumnar WO_3 film between and on ITO IDEs. Parts highlighted in reddish color indicate localized current pathways which meander with narrow necks.

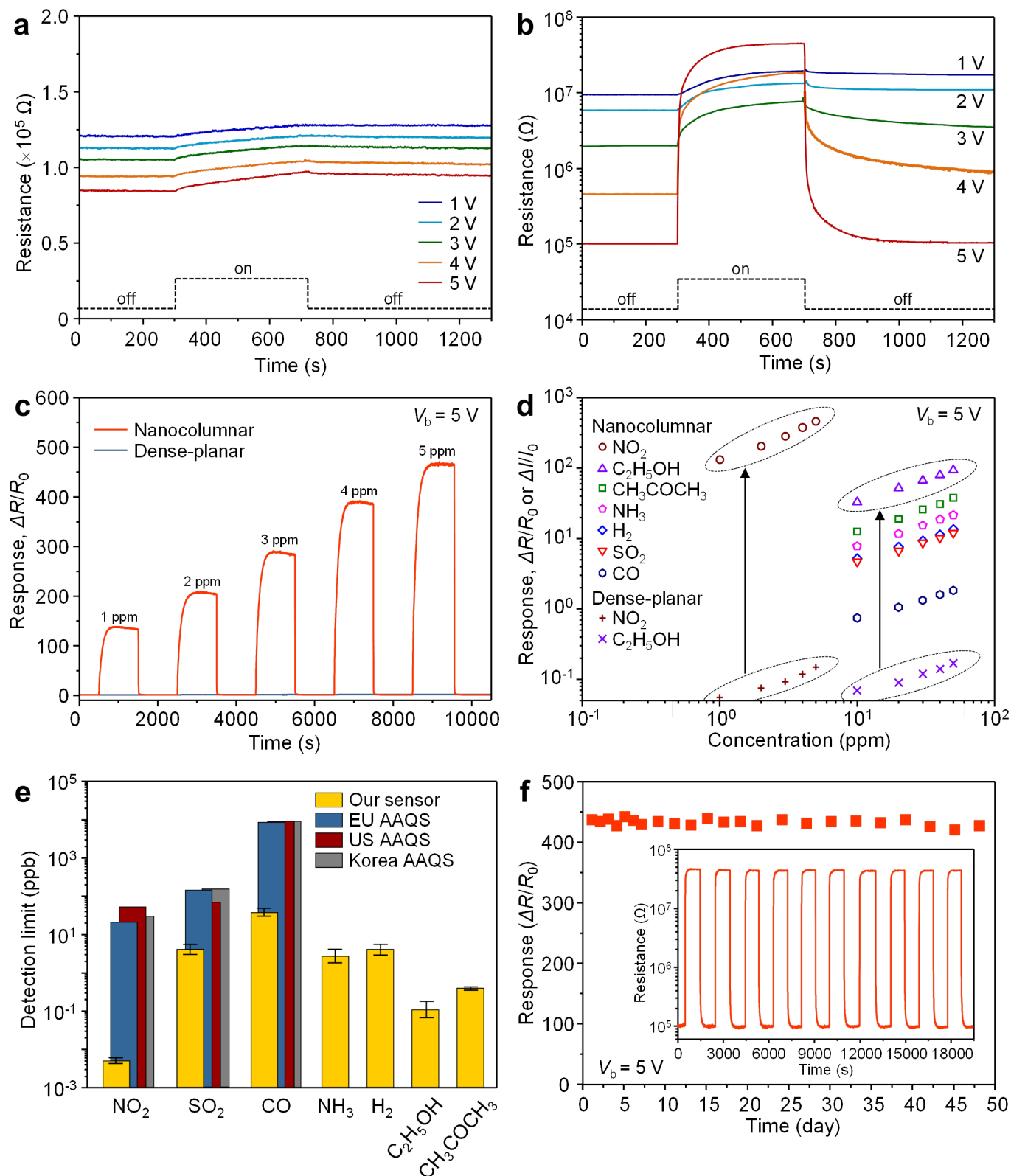


Figure 3 | Gas sensing properties. (a), (b) Dynamic sensing transients of the dense-planar (a) and nanocolumnar WO_3 thin film sensor (b) to 5 ppm NO_2 with changing applied bias from 1 to 5 V. Measurements were carried out without external heating. (c) Sensing transients of the dense-planar and nanocolumnar WO_3 thin film sensors to 1–5 ppm NO_2 at an applied bias voltage of 5 V. (d) Response of the dense-planar and nanocolumnar WO_3 thin film sensors as a function of gas concentration for various target gases. (e) Detection limits of the nanocolumnar WO_3 thin film sensor to various gases. Ambient air quality standard (AAQS) levels of European Union (EU), United States (US), and Korea for NO_2 , SO_2 , and CO are presented for comparison. The averaging periods of AAQSs for NO_2 , SO_2 , and CO are 1 year, 1 hour, and 8 hours, respectively (see Supplementary Table S1 for details). (f) Change of response of nanocolumnar thin film sensor to 5 ppm NO_2 for 48 days. Inset: response to 10 consecutive pulses of 5 ppm NO_2 after 48 days of operation.



diffraction patterns, it was revealed that the nanocolumnar WO₃ films are stoichiometric.

Discussion

Self-activation of dense-planar and nanocolumnar WO₃ thin film sensors was monitored by measuring resistance change with increasing applied voltage. Both devices displayed linear current-voltage characteristics (Supplementary Fig. S3), indicating ohmic behaviour between the WO₃ films and ITO electrodes³⁰. When the applied voltage was increased from 0.1 V to 5 V, there was a decrease by a factor of 1.45 in sensor resistance, with time transient of ~150 s, for the conventionally prepared thin film sensor (Fig. 2a). Thermographic images show that the increase in film temperature by self-activation was less than 2°C (Supplementary Fig. S4). For the same condition, the resistance of the nanocolumnar film decreased by two orders of magnitude with transient time of ~120 s. The film temperature rose to 139°C due to self-activation (Figs. 2b,c). The reduced resistance of the WO₃ film at higher temperatures reflects the semiconducting nature of WO₃. The nanocolumnar thin film device exhibits approximately two orders of magnitude higher resistance than the conventional film at the applied bias voltage of 0.1 V, but due to the pronounced self-activation of the nanocolumnar film, both devices exhibit similar values of resistance under 5 V bias. Figure 2d displays the bias voltage dependence of the specular transmittance spectra of the sensor. The small red shifts of the spectra with applied bias are consistent with a reduction in the bandgap energy of WO₃ with temperature; additional evidence for voltage-induced self-activation in the WO₃ sensing film. The absence of response to surrounding light signals (Fig. 2e) confirms that the present sensor can be used without hindrance from ambient light.

Pronounced self-activation in the nanocolumnar film originates from the unusual geometry of the film. Figure 2f shows a 40°-tilted SEM image of the nanocolumnar WO₃ film deposited between and on the ITO IDEs. The porosity of the film is estimated to be 38% on the basis of the analysis of the black and white contrast. A closer look reveals that the nanocolumns are disconnected from each other at many points and that some current pathways in the film are established only along localized regions. Even percolating pathways often meander through narrow necks (20–40 nm in width). For this geometry, electron flow is constricted, leading to increased joule heating. Furthermore, ambient air in the pores, providing an excellent thermal barrier, suppresses heat dissipation laterally to the IDEs, while the small contact area between nanocolumns and glass substrate minimizes heat dissipation to the substrate. This is in contrast to large heat losses in conventional sensors, connected with the incorporation of independent heaters screen-printed or sputtered beneath the substrate or between the sensing film and the substrate. These findings clearly demonstrate that self-assembled nanocolumnar WO₃ films serve as very efficient self-activated microheaters with minimal heat loss and power consumption. In addition to thermographic imaging, joule heating in the nanocolumnar films was confirmed by application of nanoscale electrical contact resistance (NanoECR) measurements (Supplementary Fig. S5).

Figures 3a,b show the dynamic sensing transients of the dense-planar and nanocolumnar WO₃ thin film sensors to 5 ppm NO₂ without external heating. In the case of the dense-planar sensor, the response to 5 ppm NO₂ (defined here as $\Delta R/R_0$, where R_0 and ΔR denote the initial resistance of the sensor in air and the resistance change of the sensor by exposure to the test gas, respectively) increased with increasing bias voltage (Fig. 3a). However, the response is as low as 0.15 at 5 V and the sensor does not show full recovery to the original resistance. In contrast, the nanocolumnar film sensor shows a dramatic enhancement in response with increase in bias voltage. At 5 V, the response is extremely high, ~450; the highest value ever reported, as far as we are aware, for metal oxide thin film sensors¹¹. The resistance fully recovers to the initial value

within several hundred seconds. The response time (t_{90}) that is the time for the sensor's response resistance to reach 90% of its steady-state value for the nanocolumnar film sensor is about 190 s, which is much faster than that of the dense-planar sensor ($t_{90} > 500$ s). The linear and ultra-high response of the nanocolumnar sensor to 1–5 ppm of NO₂ promises reliable detection of this environmentally important gas (Fig. 3c). In comparison, the response of the dense-planar sensor is negligibly small and sluggish, largely, attributable to the low sensing temperature and its reduced active surface area.

To verify the superior response of the nanocolumnar sensor relative to the dense-planar sensor more generally, the response to various gases such as NO₂, C₂H₅OH (ethanol), CH₃COCH₃ (acetone), NH₃, H₂, SO₂ and CO was studied. For the dense-planar sensor, the responses of the sensor to acetone, NH₃, H₂, SO₂, and CO ($\Delta I/I_0$, where I_0 and ΔI denote the initial current of the sensor in air at a fixed bias and the current change by exposure to the test gas, respectively) were close to zero while the responses to 5 ppm NO₂ and 50 ppm ethanol were lower than 0.2 (Fig. 3d). In stark contrast, ultra-high responses to all the gases were achieved by the nanocolumnar sensor (Supplementary Fig. S6). For NO₂ and ethanol, the response was three orders of magnitude higher than for that of the dense-planar sensor. This exceptional response of the nanocolumnar sensor is attributed to the combined effects of self-heating, the porous nanostructure with high surface-to-volume ratio (~33 times higher specific area than the dense-planar film) and the presence of narrow necks between the columns (Supplementary Fig. S7). Although the NO₂ concentration of 1 ppm was the lowest examined experimentally in the present study, the theoretical detection limit^{32,33} (signal-to-noise ratio > 5) was calculated to be approximately 5 parts per trillion (ppt) (Fig. 3e). This value is much lower than the ambient air quality standard (AAQS) levels of the European Union, United States and Korea, which are at several ppb levels (Supplementary Table S1). For SO₂ and CO, the detection limits of the nanocolumnar sensor are also substantially lower than the AAQS levels, suggesting strong potential of this technology serving as the basis of highly responsive air quality sensors. Furthermore, detection limits of sub-ppb levels to ethanol and acetone demonstrate the potential of the sensor for use in high performance volatile organic compound (VOC) sensors. Owing to the low working temperature (~140°C), the nanocolumnar sensor shows very stable operation as illustrated in Fig. 3f. From a comparison involving the same configuration of chemical sensors under external heating (Supplementary Fig. S8), the working temperature of the present sensor is estimated to be lower than 150°C. Meanwhile, the temperature of the backside of the sensor was measured to be 43°C during operation, at an applied bias voltage of 5 V, confirming that the present sensor design undergoes minimal heat dissipation through the substrate. With increasing the applied bias voltage, we could obtain higher responses to target gases. However, when the applied bias voltage is higher than 7 V, the working temperature of the sensor becomes higher than 200°C. As we discussed earlier, such a high working temperature should come at a cost to long-term reliability probably along with morphological changes in the sensing film. This suggests that the applied bias voltage bias should be adjusted so that the working temperature may not exceed 200°C.

In addition to high sensitivity and long-term reliability, low power consumption is required for practical applications of the nanocolumnar sensors as a component in handheld devices such as mobile phones. To address this issue, we have measured power consumption of the sensors with changing the area of sensing film and the duty cycle of pulsed bias voltage. Figure 4a shows the power consumption of nanocolumnar sensors as a function of sensing area. By reducing the area of the WO₃ sensing film from 1 mm × 1 mm to 100 μm × 170 μm (Supplementary Fig. S9), the response of the sensors remains nearly constant, while the power consumption decreases from 251 μW to 21.6 μW. These values are much lower than the power



consumption of even micromachined thin film sensors (5–200 mW)^{16,34} and comparable to those of self-heated single nanowire sensors (tens of μW)¹⁷. When the response of the sensor with $100\ \mu\text{m} \times 170\ \mu\text{m}$ sensing area is normalized with respect to the power consumption, it exhibits incomparably superior performance to the state-of-art chemoresistive sensors (Supplementary Fig. S10). The power consumption of the sensor could be further lowered using pulsed mode operation, as shown in Fig. 4b. When the duty cycle of the pulsed bias voltage is reduced down to 4%, the sensor still exhibits excellent sensing performance with moderate decreases in response and response speed (Supplementary Fig. S11). The strikingly low power consumption, 0.18 μW , of the sensor at a 4% duty cycle means that the sensors can operate for a half year using a commercially available lithium polymer cell phone battery (output voltage: 3.7 V DC, capacity 1500 mAh). These results demonstrate the overall superior performance of the nanocolumnar WO_3 thin film sensors and their remarkably low power requirements point to the feasibility of embedding them into miniature, portable devices.

In conclusion, we have realized all oxide transparent chemoresistive sensors with ultrahigh sensitivity, extremely low power consumption and excellent long-term stability by utilization of uniquely nanostructured metal oxide thin films, which are readily

self-activated with μA current and 0.1's of μW power levels. The remarkable device performance, achieved with a facile fabrication process, considerably broadens the potential application of chemoresistive sensors to transparent electronics and highly miniaturized mobile devices. We believe that very high performance portable *electronic noses* with selective chemical sensing can be developed by integrating multiple sensors of our design onto a single sensor platform coupled with the adoption of surface decoration^{35,36} and temperature variation³⁷ techniques. The approach, successfully demonstrated in this work for miniaturized chemoresistive gas sensors, can be extended, we believe, to improve the performance of other solid-state devices such as fuel cells, CO_2 reduction systems and other types of sensors that operate at elevated temperatures by removing separate heating elements and exploiting the self-activation capacity of active elements within the device structure.

Methods

Sensor fabrication. ITO (150 nm thick, $10\ \Omega/\square$) IDE patterns of $5\ \mu\text{m}$ spacing were fabricated on glass substrates using photolithography and dry etching. After patterning the ITO IDEs, a 330 nm thick WO_3 film was deposited onto predefined regions by a shadow mask on the ITO-IDE-patterned glass substrate using room-temperature RF sputtering, where a polycrystalline WO_3 target was utilized for film deposition. To render the film porous, the sputtering deposition was carried out at a glancing angle of 5° . The base pressure, working pressure, RF power, and gas flow rate were 2×10^{-6} mTorr, 3 mTorr, 300 W and 30 sccm, respectively. The deposition rate of the film was 8 nm/min. The fabricated $\text{WO}_3/\text{ITO}/\text{glass}$ sensor structure was annealed in air at 500°C for 60 min to crystallize the amorphous WO_3 film. For comparison, a planar WO_3 thin film sensor was fabricated using on-axis RF sputtering, which leads to the deposition of a 330 nm thick dense WO_3 film.

Characterization. The morphologies of the fabricated sensors were characterized by SEM (XL30 FEG ESEM, FEI) using 15 kV voltage. TEM images were taken by a JEOL JEM 2100F with a probe-Cs corrector. Cross-sectional TEM specimens of WO_3 nanocolumns on a glass substrate were prepared by mechanical polishing followed by ion milling with Ar ions. The crystallinity and phase of the sensor films were characterized by glancing angle X-ray diffraction (D/Max-2500, Rigaku), where $\text{Cu K}\alpha$ radiation (wavelength = 1.5418 Å) was used for the X-ray source and the incident angle was fixed at a small angle (2°). For all the WO_3 sensing films, selected area electron diffraction patterns from TEM and X-ray diffraction patterns could be indexed with the pure monoclinic phase of WO_3 with lattice constants $a = 5.261\ \text{\AA}$, $b = 5.128\ \text{\AA}$, $c = 7.650\ \text{\AA}$ and $\beta = 92.05^\circ$ (JCPDS #88-0550). Thermographic images of the sensors were obtained with an infrared camera (SC5000, FLIR). The transmittance of the entire sensor structures was measured over the wavelength range of 200–900 nm by UV/VIS spectrometry (Lambda 18, Perkin Elmer). NanoECR measurements were carried out using a nanomechanical test instrument (TI 750 Ubi, Hysitron).

Sensor measurements. The gas sensing properties of the fabricated thin film sensors were measured without external heating. As the flow gas was changed from dry air to a calibrated test gas (balanced with dry air, Sinyang Gases), the variation in sensor resistance was monitored using a source measurement unit (Keithley 236). A constant flow rate of 500 sccm was used for dry air and the test gas. The sensor resistance was measured under a DC bias voltage of 0.1–5 V. The response of the sensors ($\Delta R/R_0$ for NO_2 , AlI_0 for ethanol, acetone, SO_2 , NH_3 , H_2 , and CO) was accurately determined by measuring the baseline resistances of the sensors in dry air and the fully saturated resistances after exposure to the test gas. Gas flow was controlled using mass flow controllers, and all measurements were recorded to a computer through the use of LabVIEW over a GPIB interface. The current–voltage characteristics of the fabricated sensors were measured to check the contribution of the contact resistance between ITO IDEs and the WO_3 sensing film to the overall performance. For the pulse mode operation, the pulse period of 5 ms was used and the pulse duration was changed from 1.25 ms (25% duty cycle) to 0.2 ms (4% duty cycle). Additional experimental details about sensor measurements may be found in our previous reports^{38,39}.

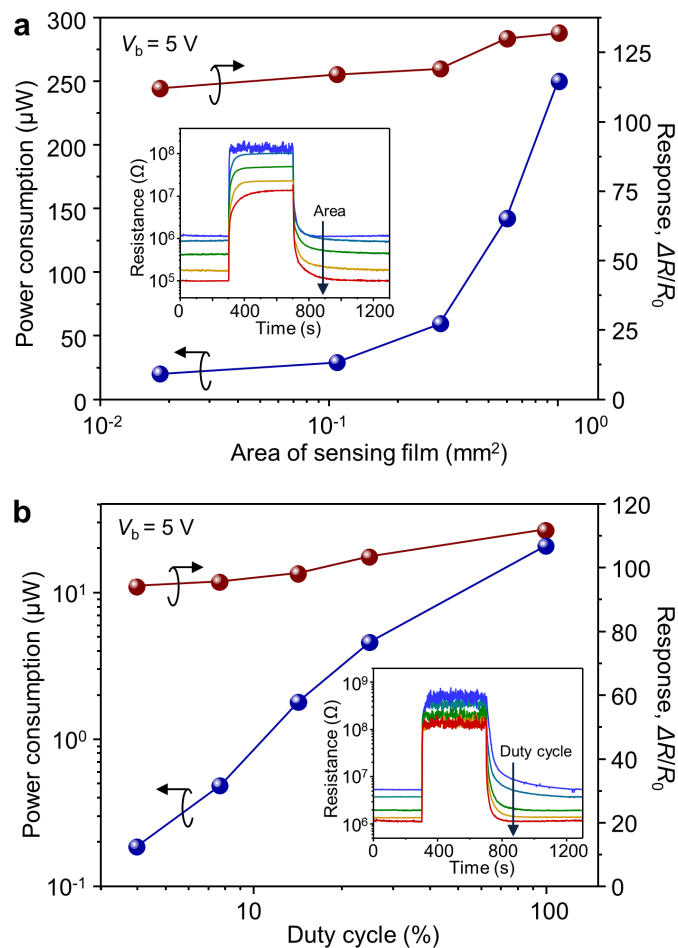


Figure 4 | Power consumption. (a) Power consumption and response of nanocolumnar WO_3 thin film sensors to 1 ppm NO_2 as a function of the area of sensing film. Inset: response transients to 1 ppm NO_2 of sensors with different areas of sensing film. (b) Power consumption and response of the nanocolumnar WO_3 thin film sensor with $100\ \mu\text{m} \times 170\ \mu\text{m}$ sensing area to 1 ppm NO_2 as a function of the duty cycle of pulsed bias voltage. For each duty cycle, the pulse period is 5 ms. Inset: response transients to 1 ppm NO_2 of the sensor with changing the duty cycle.

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Author contributions

H.G.M. performed film deposition, characterizations and sensor measurements. Y.S.S. and D.H.K. fabricated the sensors. H.Y.J. and M.J. carried out TEM measurements. J.Y.J. and S.M.H. conducted NanoECR measurements. J.K.K., J.S.K., H.H.P., J.H.L., H.W.J. and S.J.Y. supervised the experiments and contributed to manuscript preparation. H.G.M., J.K.K., J.H.L., H.W.J., S.J.Y. and H.L.T. analysed the data and wrote the manuscript. H.L.T. provided advice for the research. S.J.Y. and H.W.J. initiated and directed the research. H.W.J. conceived the idea and designed the experiments. All authors discussed the progress of research and reviewed the manuscript.

Additional information

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